# 

# Low-Power, 14-Bit Analog-to-Digital Converters with Parallel Interface

### **General Description**

The MAX1065/MAX1066 14-bit, low-power successive approximation analog-to-digital converters (ADCs) feature automatic power-down, a factory-trimmed internal clock, and a high-speed, 14-bit-wide (MAX1065) or byte-wide (MAX1066) parallel interface. The devices operate from a single 4.75V to 5.25V analog supply and a 2.7V to 5.25V digital supply.

The MAX1065/MAX1066 use an internal 4.096V reference or an external reference. The MAX1065/MAX1066 consume only 1.8mA at a sampling rate of 165ksps with external reference and 2.7mA with internal reference. AutoShutdown<sup>™</sup> reduces supply current to 0.1mA at 10ksps.

The MAX1065/MAX1066 are ideal for high-performance, battery-powered, data-acquisition applications. Excellent dynamic performance and low-power consumption in a small package make the MAX1065/ MAX1066 the best choice for circuits with demanding power consumption and space requirements.

The 14-bit-wide MAX1065 is available in a 28-pin TSSOP package, and the byte-wide MAX1066 is available in a 20-pin TSSOP package. Both devices are available in either the 0°C to +70°C commercial, or the -40°C to +85°C extended temperature range.

### \_Applications

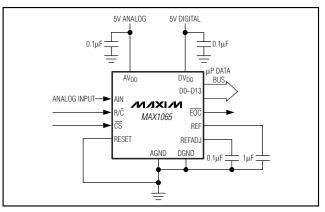
Temperature Sensor/Monitor Industrial Process Control Cable/Harness Tester Accelerometer Measurements Digital Signal Processing

I/O Boards

Data-Acquisition Systems

**MIXIM** 

## **Typical Operating Circuit**



### **Features**

- 14-Bit-Wide (MAX1065) and Byte-Wide (MAX1066) Parallel Interface
- High Speed: 165ksps Sample Rate
- Accurate: ±1LSB DNL (max), ±1LSB INL (max)
- ♦ 4.096V, 35ppm/°C Internal Reference
- ♦ External Reference Range 3.8V to 5.25V
- Single 4.75V to 5.25V Analog Supply Voltage
- ♦ 2.7V to 5.25V Digital Supply Voltage
- Low Supply Current

   1.8mA (External Reference)
   2.7mA (Internal Reference)
   0.1mA AutoShutdown Mode (10ksps, External Reference)
- Small Footprint 28-Pin TSSOP Package (14-Bit Wide) 20-Pin TSSOP Package (Byte Wide)

### **Ordering Information**

PART	TEMP RANGE	PIN- PACKAGE	INL
MAX1065ACUI	0°C to 70°C	28 TSSOP	±1
MAX1065BCUI	0°C to 70°C	28 TSSOP	±2
MAX1065CCUI	0°C to 70°C	28 TSSOP	±3
MAX1065AEUI	-40°C to +85°C	28 TSSOP	±1
MAX1065BEUI	-40°C to +85°C	28 TSSOP	±2
MAX1065CEUI	-40°C to +85°C	28 TSSOP	±3
MAX1066ACUP	0°C to 70°C	20 TSSOP	±1
MAX1066BCUP	0°C to 70°C	20 TSSOP	±2
MAX1066CCUP	0°C to 70°C	20 TSSOP	±3
MAX1066AEUP	-40°C to +85°C	20 TSSOP	±1
MAX1066BEUP	-40°C to +85°C	20 TSSOP	±2
MAX1066CEUP	-40°C to +85°C	20 TSSOP	±3

### Pin Configurations appear at end of data sheet.

AutoShutdown is a registered trademark of Maxim Integrated Products, Inc.

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For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

### **ABSOLUTE MAXIMUM RATINGS**

AV <sub>DD</sub> to AGND	0.3V to +6V
DV <sub>DD</sub> to DGND	
AGND to DGND	0.3V to +0.3V
AIN, REF, REFADJ to AGND	0.3V to (AV <sub>DD</sub> + 0.3V)
CS, HBEN, R/C, RESET to DGND	0.3V to +6V
Digital Output (D13–D0, EOC)	
to DGND	0.3V to (DV <sub>DD</sub> + 0.3V)
Maximum Continuous Current Into An	y Pin50mA

Continuous Power Dissipation (T <sub>A</sub> = +70°C) 20-Pin TSSOP (derate 10.9mW/°C above +70°C)879mW 28-Pin TSSOP (derate 12.8mW/°C above +70°C)1026mW
Operating Temperature Ranges MAX106CU0°C to +70°C MAX106EU40°C to +85°C
Storage Temperature Range65°C to +150°C Junction Temperature+150°C Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

 $(AV_{DD} = DV_{DD} = 5V$ , external reference = 4.096V, CREF = 1µF, CREFADJ = 0.1µF, TA = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DC ACCURACY						
Resolution	Ν		14			Bits
		MAX106_A			±1	
Relative Accuracy (Note 1)	INL	MAX106_B			±2	LSB
		MAX106_C			±3	]
Differential Nonlinearity	DNL	No missing codes over temperature			±1	LSB
Transition Noise		RMS noise, includes quantization noise		0.32		LSB <sub>RMS</sub>
Offset Error				0.2	1	mV
Gain Error		(Note 2)		±0.002	±0.02	%FSR
Offset Drift				0.6		ppm/°C
Gain Drift				0.2		ppm/°C
DYNAMIC PERFORMANCE (fin	(SINE-WAVE) =	1kHz, V <sub>IN</sub> = 4.096V <sub>P-P</sub> , 165ksps)				
Signal-to-Noise Plus Distortion	SINAD		81	84		dB
Signal-to-Noise Ratio	SNR		82	84		dB
Total Harmonic Distortion	THD			-99	-86	dB
Spurious-Free Dynamic Range	SFDR		87	102		dB
Full-Power Bandwidth		-3dB point		4		MHz
Full-Linear Bandwidth		SINAD > 81dB		20		kHz
CONVERSION RATE						
Sample Rate	<b>f</b> SAMPLE				165	ksps
Aperture Delay				40		ns
Aperture Jitter				100		ps
ANALOG INPUT						
Input Range	VAIN		0		V <sub>REF</sub>	V
Input Capacitance	CAIN			40		рF

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(AV_{DD} = DV_{DD} = 5V$ , external reference = 4.096V,  $C_{REF} = 1\mu$ F,  $C_{REFADJ} = 0.1\mu$ F,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}$ C.)

PARAMETER	SYMBOL	CONDIT	TIONS	MIN	TYP	MAX	UNITS
INTERNAL REFERENCE				•			•
REF Output Voltage	VREF			4.056	4.096	4.136	V
REF Output Tempco	TCREF				±35		ppm/°C
REF Short-Circuit Current	IREFSC				±10		mA
Capacitive Bypass at REFADJ	Crefadj			0.1			μF
Capacitive Bypass at REF	CREF			1			μF
REFADJ Input Leakage Current	IREFADJ				20		μA
EXTERNAL REFERENCE		·					
REFADJ Buffer Disable Threshold		To power-down the i	nternal reference	AV <sub>DD</sub> - 0.4		AV <sub>DD</sub> - 0.1	V
REF Input Voltage Range		Internal reference dis	sabled	3.8		AV <sub>DD</sub>	V
		V <sub>REF</sub> = 4.096V, f <sub>SAM</sub>	PLE = 165ksps		62	120	
REF Input Current	IREF	Shutdown mode			±0.1		μA
DIGITAL INPUTS/OUTPUTS (CS	S, R/C, EOC, D	0–D13, RESET, HBEN)	)	1			
Input High Voltage	VIH			0.7 x DV <sub>DD</sub>			V
Input Low Voltage	VIL					0.3 x DV <sub>DD</sub>	v
Input Leakage Current	liN	$V_{IH} = 0 \text{ or } DV_{DD}$			±0.1	±1	μA
Input Hysteresis	V <sub>HYST</sub>				0.1		V
Input Capacitance	CIN				15		pF
Output High Voltage	V <sub>OH</sub>	$I_{SOURCE} = 0.5mA,$ $DV_{DD} = 2.7V \text{ to } 5.25'$ $AV_{DD} = 5.25V$	V,	D <sub>VDD</sub> - 0.4			V
Output Low Voltage	V <sub>OL</sub>	$I_{SINK} = 1.6 mA,$ $DV_{DD} = 2.7V to 5.25V,$ $AV_{DD} = 5.25V$				0.4	V
Three-State Leakage Current	I <sub>OZ</sub>	D0-D13			±0.1	±10	μΑ
Three-State Output Capacitance	C <sub>OZ</sub>				15		pF
POWER REQUIREMENTS							
Analog Supply Voltage	AV <sub>DD</sub>			4.75		5.25	V
Digital Supply Voltage	DVDD			2.7		AV <sub>DD</sub>	V
			165ksps		2.7	3.2	
		Internal references	100ksps		2.0		
		Internal reference	10ksps		1.0		
Analog Supply Current	L		1ksps		1.0		
Analog Supply Current	I <sub>AVDD</sub>		165ksps		1.8	2.3	mA
		Evtornal reference	100ksps		1.1		
		External reference	10ksps		0.1		
			1ksps		0.01		

# MAX1065/MAX1066

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(AV_{DD} = DV_{DD} = 5V, external reference = 4.096V, C_{REF} = 1\mu F, C_{REFADJ} = 0.1\mu F, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C.$ )

PARAMETER	SYMBOL	CONDIT	IONS	MIN	ТҮР	MAX	UNITS
			165ksps		0.5	0.7	
Digital Supply Current		D0–D13 = all zeros	100ksps		0.3		mA
Digital Supply Current	IDVDD	D0-D13 = all zeros	10ksps		0.03		
			1ksps		0.003		
Shutdown Supply Current (Note 3)	ISHDN	Full power-down	IAVDD		0.05	5	mA
			IDVDD		0.5	5	μA
		REF and REF buffer enabled (standby mode)	I <sub>AVDD</sub>		1.0	1.2	mA
			IDVDD		0.5	5	μA
Power-Supply Rejection Ratio (Note 4)	PSRR	$AV_{DD} = 5V, \pm 5\%$ , full-scale input			68		dB

### TIMING CHARACTERISTICS (Figures 1 and 2)

(AV<sub>DD</sub> = 4.75V to 5.25V, DV<sub>DD</sub> = 2.7V to AV<sub>DD</sub>, external reference = 4.096V, C<sub>REF</sub> = 1 $\mu$ F, C<sub>REFADJ</sub> = 0.1 $\mu$ F, C<sub>D13-D0</sub>, C<sub>EOC</sub> = 20pF, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL		CONDITIONS	MIN	ТҮР	MAX	UNITS	
Acquisition Time	tacq			1.1				
Conversion Time	tCONV					4.7	μs	
CS Pulse Width High	tCSH	(Note 5)		40			ns	
$\overline{\text{CS}}$ Pulse Width Low	<b>t</b> = = :	(Nista C)	V <sub>DVDD</sub> = 4.75V to 5.25V	40				
CS Pulse Width Low	tCSL	(Note 5)	$V_{DVDD} = 2.7V \text{ to } 4.74V$	60			ns	
$R/\overline{C}$ to $\overline{CS}$ Fall Setup Time	tDS			0			ns	
$R/\overline{C}$ to $\overline{CS}$ Fall Hold Time	t	V <sub>DVDD</sub> =	4.75V to 5.25V	40			20	
n/C to C3 Fall Hold Time	tDH	V <sub>DVDD</sub> =	2.7V to 5.25V	60			ns	
$\overline{\text{CS}}$ to Output Data Valid		V <sub>DVDD</sub> =	4.75V to 5.25V			40	20	
CS to Output Data Valid	tdo	$V_{\text{DVDD}} = 2.7 \text{V} \text{ to } 4.74 \text{V}$				80	ns	
HBEN Transition To		V <sub>DVDD</sub> = 4.75V to 5.25V				40	ns	
Output Data Valid (MAX1066 only)	tDO1	V <sub>DVDD</sub> =	2.7V to 4.74V			80	115	
$\overline{\text{EOC}}$ Fall To $\overline{\text{CS}}$ Fall	t <sub>DV</sub>			0			ns	
CS Rise To EOC Rise	teoc	V <sub>DVDD</sub> = 4.75V to 5.25V				40		
		V <sub>DVDD</sub> =	2.7V to 4.74V			80	ns	
Bus Relinquish Time	top	V <sub>DVDD</sub> = 4.75V to 5.25V				40		
(Note 5)	tBR	V <sub>DVDD</sub> =	2.7V to 4.74V			80	ns	

Note 1: Relative accuracy is the deviation of the analog value at any code from its theoretical value after offset and gain errors have been removed.

Note 2: Offset nulled.

Note 3: Maximum specification is limited by automated test equipment.

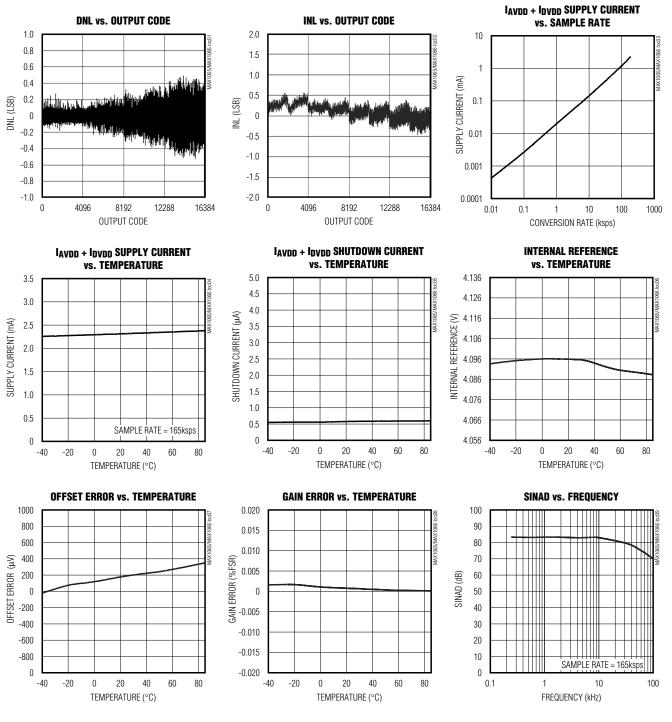
**Note 4:** Defined as the change in positive full scale caused by a ±5% variation in the nominal supply.

Note 5: To ensure best performance, finish reading the data and wait  $t_{BR}$  before starting a new acquisition.



### \_Typical Operating Characteristics

 $(AV_{DD} = DV_{DD} = 5V, external reference = 4.096V, C_{REF} = 1\mu F, C_{REFADJ} = 0.1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$ 



/M/IXI/M \_\_\_

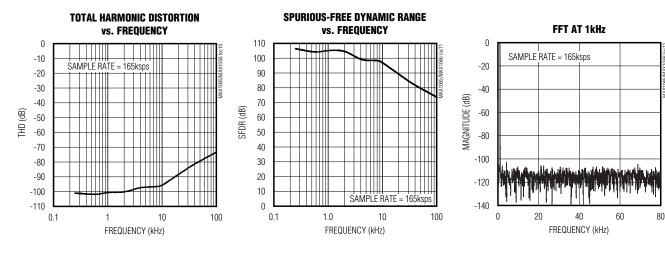
MAX1065/MAX1066

5

# MAX1065/MAX1066



 $(AV_{DD} = DV_{DD} = 5V, \text{ external reference} = 4.096V, C_{REF} = 1\mu F, C_{REFADJ} = 0.1\mu F, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 



### Pin Description

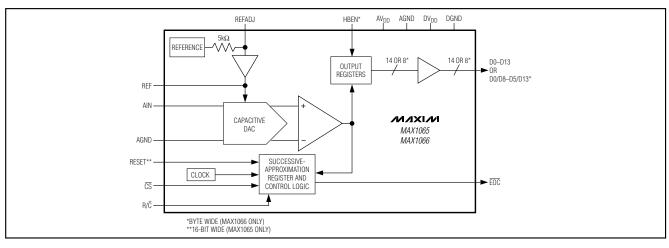
P	N	NAME		FUNCTION
MAX1065	MAX1066	MAX1065	MAX1066	FUNCTION
1	1	D6	D4/D12	Three-State Digital Data Output
2	2	D7	D5/D13	Three-State Digital Data Output. D13 is the MSB.
3	3	D8	D6/0	Three-State Digital Data Output
4	4	D9	D7/0	Three-State Digital Data Output
5		D10	_	Three-State Digital Data Output
6	_	D11	_	Three-State Digital Data Output
7		D12	_	Three-State Digital Data Output
8	_	D13	_	Three-State Digital Data Output (MSB)
9	5	R/C		Read/ $\overline{\text{Convert}}$ Input. Power up and put the MAX1065/MAX1066 in acquisition mode by holding R/ $\overline{\text{C}}$ low during the first falling edge of $\overline{\text{CS}}$ . During the second falling edge of $\overline{\text{CS}}$ the level on R/ $\overline{\text{C}}$ determines whether the reference and reference buffer power down or remain on after conversion. Set R/ $\overline{\text{C}}$ high during the second falling edge of $\overline{\text{CS}}$ to power down the reference and buffer, or set R/ $\overline{\text{C}}$ low to leave the reference and buffer powered up. Set R/ $\overline{\text{C}}$ high during the third falling edge of $\overline{\text{CS}}$ to put valid data on the bus.
10	6	ĒC	DC	End Of Conversion. EOC drives low when conversion is complete.
11	7	AV	DD	Analog Supply Input. Bypass with a 0.1µF capacitor to AGND.
12	8	AGND		Analog Ground. Primary analog ground (star ground).
13	9	AIN		Analog Input
14	10	AGND		Analog Ground. Connect Pin 14 to Pin 12 (MAX1065). Connect Pin 10 to Pin 8 (MAX1066).

## Pin Description (continued)

Р	PIN NAME		PIN		ME	
MAX1065	MAX1066	MAX1065	MAX1066	FUNCTION		
15	11	REFADJ		Reference Buffer Output. Bypass REFADJ with a $0.1\mu$ F capacitor to AGND for internal reference mode. Connect REFADJ to AV <sub>DD</sub> to select external reference mode.		
16	12	REF		Reference Input/Output. Bypass REF with a 1µF capacitor to AGND for internal reference mode. External reference input when in external reference mode.		
17		RE	SET	Reset Input. Logic high resets the device.		
_	13	HBEN		High Byte-Enable Input. Used to multiplex the 14-bit conversion result. 1: Most significant byte available on the data bus. 0: Least significant byte available on the data bus.		
18	14	CS		Convert Start. The first falling edge of $\overline{CS}$ powers up the device and enables acquire mode when R/ $\overline{C}$ is low. The second falling edge of $\overline{CS}$ starts conversion. The third falling edge of $\overline{CS}$ loads the result onto the bus when R/ $\overline{C}$ is high.		
19	15	DG	iND	Digital Ground		
20	16	D۷	DD	Digital Supply Voltage. Bypass with a 0.1µF capacitor to DGND.		
21	17	N.C.	D0/D8	No Connection. Do Not Connect (MAX1065). Three-State Digital Data Output (MAX1066).		
22	18	N.C. D1/D9		No Connection. Do Not Connect (MAX1065). Three-State Digital Data Output (MAX1066).		
23	19	D0	D2/D10	Three-State Digital Data Output		
24	20	D1 D3/D11		Three-State Digital Data Output		
25		D2 —		Three-State Digital Data Output		
26		D3 —		Three-State Digital Data Output		
27	_	D4	_	Three-State Digital Data Output		
28	—	D5	_	Three-State Digital Data Output		

# MAX1065/MAX1066

### **Functional Diagram**



### **Detailed Description**

### **Converter Operation**

The MAX1065/MAX1066 use a successive-approximation (SAR) conversion technique with an inherent track-andhold (T/H) stage to convert an analog input into a 14-bit digital output. Parallel outputs provide a high-speed interface to most microprocessors ( $\mu$ Ps). The *Functional Diagram* shows a simplified internal architecture of the MAX1065/MAX1066. Figure 3 shows a typical application circuit for the MAX1066.

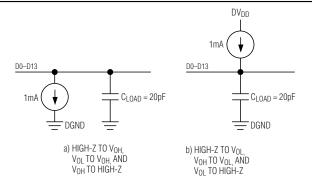


Figure 1. Load Circuits for D0–D13 Enable Time,  $\overline{CS}$  to D0–D13 Delay Time and Bus Relinquish Time

### Analog Input

The equivalent input circuit is shown in Figure 4. A switched capacitor digital-to-analog converter (DAC) provides an inherent track-and-hold function. The single-ended input is connected between AIN and AGND.

### Input Bandwidth

The ADC's input-tracking circuitry has a 4MHz smallsignal bandwidth, so it is possible to digitize highspeed transient events and measure periodic signals with bandwidths exceeding the ADC's sampling rate by using undersampling techniques. To avoid aliasing of unwanted high-frequency signals into the frequency band of interest, use antialias filtering.

Internal protection diodes, which clamp the analog input to AV<sub>DD</sub> and/or AGND, allow the input to swing from AGND - 0.3V to AV<sub>DD</sub> + 0.3V, without damaging the device.

If the analog input exceeds 300mV beyond the supplies, limit the input current to 10mA.

### Track and Hold (T/H)

In track mode, the analog signal is acquired on the internal hold capacitor. In hold mode, the T/H switches open and the capacitive DAC samples the analog input.

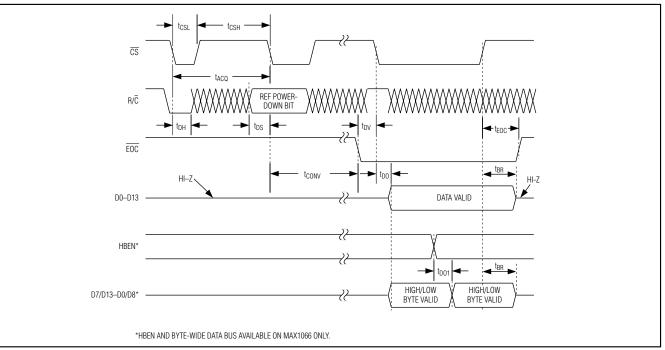


Figure 2. MAX1065/MAX1066 Timing Diagram

During the acquisition, the analog input (AIN) charges capacitor  $C_{DAC}$ . The acquisition ends on the second falling edge of  $\overline{CS}$ . At this instant, the T/H switches open. The retained charge on  $C_{DAC}$  represents a sample of the input.

In hold mode, the capacitive DAC adjusts during the remainder of the conversion time to restore node ZERO to zero within the limits of 14-bit resolution. At the end of the conversion, force  $\overline{CS}$  low to put valid data on the bus.

The time required for the T/H to acquire an input signal is a function of how quickly its input capacitance is charged. If the input signal's source impedance is high, the acquisition time lengthens and more time must be allowed between conversions. The acquisition time ( $t_{ACQ}$ ) is the maximum time the device takes to acquire the signal. Use the following formula to calculate acquisition time:

 $t_{ACQ} = 11(R_S + R_{IN}) \times 35pF$ 

where  $R_{IN} = 800\Omega$ ,  $R_S =$  the input signal's source impedance, and  $t_{ACQ}$  is never less than 1.1µs. A source impedance less than 1k $\Omega$  does not significantly affect the ADC's performance.

To improve the input-signal bandwidth under AC conditions, drive AIN with a wideband buffer (>4MHz) that can drive the ADC's input capacitance and settle quickly.

### **Power-Down Modes**

Select standby mode or shutdown mode with the R/C bit during the second falling edge of  $\overline{CS}$  (see *Selecting Standby or Shutdown Mode* section). The MAX1065/MAX1066 automatically enter either standby mode, reference and buffer on, or shutdown, reference and buffer off, after each conversion depending on the status of R/C during the second falling edge of  $\overline{CS}$ .

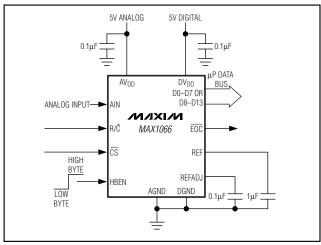


Figure 3. Typical Application Circuit for MAX1066

### **Internal Clock**

The MAX1065/MAX1066 generate an internal conversion clock. This frees the microprocessor from the burden of running the SAR conversion clock. Total conversion time after entering hold mode (second falling edge of  $\overline{\text{CS}}$ ) to end-of-conversion (EOC) falling is 4.7µs (max).

### Applications Information

### Starting a Conversion

 $\overline{\text{CS}}$  and  $\overline{\text{R/C}}$  control acquisition and conversion in the MAX1065/MAX1066 (Figure 2). The first falling edge of  $\overline{\text{CS}}$  powers up the device and puts it into acquisition mode if  $\overline{\text{R/C}}$  is low. The convert start is ignored if  $\overline{\text{R/C}}$  is high. When powering up from shutdown, the MAX1065/MAX1066 needs at least 10ms ( $\overline{\text{CREFADJ}} = 0.1\mu\text{F}$ ,  $\overline{\text{CREF}} = 1\mu\text{F}$ ) for the internal reference to wake up and settle before starting the conversion. The ADC may wake up from shutdown to an unknown state. Put the ADC in a known state by completing one "dummy" conversion. The MAX1065/ MAX1066 will be in a known state, ready for actual data acquisition, after the completion of the dummy conversion. A dummy conversion consists of one full conversion cycle.

The MAX1065 provides an alternative reset function to reset the device (see *RESET* section).

Selecting Standby or Shutdown Mode The MAX1065/MAX1066 have a selectable standby or low-power shutdown mode. In standby mode, the ADC's internal reference and reference buffer do not power down between conversions, eliminating the need to wait for the reference to power up before performing the next conversion. Shutdown mode powers down the reference and reference buffer after completing a conversion. Supply current is greatly reduced when in shutdown mode. The reference and reference buffer require a minimum of 10ms (CREFADJ =  $0.1\mu$ F, CREF =  $1\mu$ F) to power up and settle from shutdown.

The state of  $R/\overline{C}$  at the second falling edge of  $\overline{CS}$  selects which power-down mode the MAX1065/ MAX1066 enters upon conversion completion. Holding  $R/\overline{C}$  low causes the MAX1065/MAX1066 to enter standby mode. The reference and buffer are left on after the conversion completes.  $R/\overline{C}$  high causes the MAX1065/MAX1066 to enter shutdown mode and shut down the reference and buffer after conversion (Figures 5 and 6).

When using an external reference, set the REF powerdown bit high for lowest current operation.

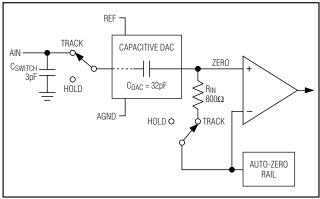


Figure 4. Equivalent Input Circuit

### **Standby Mode**

While in standby mode, the supply current is reduced to less than 1mA (typ). The next falling edge of  $\overline{CS}$  with  $R/\overline{C}$  low causes the MAX1065/MAX1066 to exit standby mode and begin acquisition. The reference and reference buffer remain active to allow quick turn-on time. Standby mode allows significant power savings while running at the maximum sample rate.

### Shutdown Mode

In shutdown mode, the reference and reference buffer are shut down between conversions. Shutdown mode reduces supply current to  $0.5\mu$ A (typ) immediately after the conversion. The falling edge of  $\overline{CS}$  with R/C low causes the reference and buffer to wake up and enter acquisition mode. To achieve 14-bit accuracy, allow 10ms (C<sub>REFADJ</sub> =  $0.1\mu$ F, C<sub>REF</sub> =  $1\mu$ F) for the internal reference to wake up. Increase wakeup time proportionally when using larger values of C<sub>REFADJ</sub> and C<sub>REF</sub>.

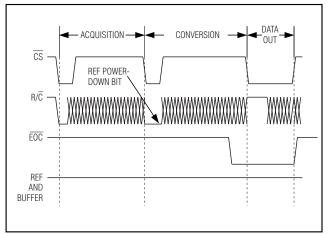


Figure 5. Selecting Standby Mode

### **Internal and External Reference**

### Internal Reference

The internal reference of the MAX1065/MAX1066 is internally buffered to provide 4.096V (typ) output at REF. Bypass REF to AGND and REFADJ to AGND with  $1\mu$ F and 0.1 $\mu$ F respectively. Fine adjustments can be made to the internal reference voltage by sinking or sourcing current at REFADJ. The input impedance at REFADJ is nominally 5k $\Omega$ . The internal reference voltage is adjustable to ±1.5% with the circuit of Figure 7.

### **External Reference**

///XI//

An external reference can be placed at either the input (REFADJ) or the output (REF) of the MAX1065/ MAX1066's internal buffer amplifier. When connecting an external reference to REFADJ, the input impedance is typically  $5k\Omega$ . Using the buffered REFADJ input makes buffering the external reference unnecessary; however, the internal buffer output must be bypassed at REF with a 1µF capacitor.

Connect REFADJ to AV\_DD to disable the internal buffer. Directly drive REF using an external reference. During conversion, the external reference must be able to drive 100µA of DC load current and have an output impedance of 10 $\Omega$  or less. REFADJ's impedance is typically 5k $\Omega$ . The DC input impedance of REF is 40k $\Omega$  minimum.

For optimal performance, buffer the reference through an op amp and bypass REF with a 1 $\mu$ F capacitor. Consider the MAX1065/MAX1066's equivalent input noise (80 $\mu$ V<sub>RMS</sub>) when choosing a reference.

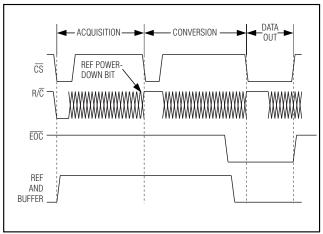
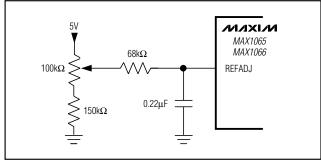


Figure 6. Selecting Shutdown Mode





### **Reading the Conversion Result**

EOC is provided to flag the microprocessor when a conversion is complete. The falling edge of EOC signals that the data is valid and ready to be output to the bus.

D0–D13 are the parallel outputs of the MAX1065/ MAX1066. These three-state outputs allow for direct connection to a microcontroller I/O bus. The outputs remain high-impedance during acquisition and conversion. Data is loaded onto the bus with the third falling edge of  $\overline{CS}$  with R/C high after t<sub>D</sub>Ons. Bringing  $\overline{CS}$  high forces the output bus back to high-impedance. The MAX1065/MAX1066 then waits for the next falling edge of  $\overline{CS}$  to start the next conversion cycle (Figure 2).

The MAX1065 loads the conversion result onto a 14-bitwide data bus while the MAX1066 has a byte-wide output format. HBEN toggles the output between the most/least significant byte. The least significant byte is loaded onto the output bus when HBEN is low and the most significant byte is on the bus when HBEN is high (Figure 2).

### RESET

Toggle RESET with  $\overline{CS}$  high. The next falling edge of  $\overline{CS}$  will begin acquisition. This reset is an alternative to the dummy conversion explained in the *Starting a Conversion* section.

### **Transfer Function**

Figure 8 shows the MAX1065/MAX1066 output transfer function. The output is coded in standard binary.

### **Input Buffer**

Most applications require an input buffer amplifier to achieve 14-bit accuracy. If the input signal is multiplexed, the input channel should be switched immediately after acquisition, rather than near the end of or after a conversion. This allows more time for the input buffer amplifier to respond to a large step-change in input signal. The input amplifier must have a high enough slew rate to complete

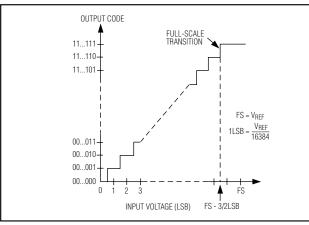


Figure 8. MAX1065/MAX1066 Transfer Function

the required output voltage change before the beginning of the acquisition time. At the beginning of acquisition, the internal sampling capacitor array connects to AIN (the amplifier output) causing some output disturbance. Ensure that the sampled voltage has settled to within the required limits before the end of the acquisition time. If the frequency of interest is low, AIN can be bypassed with a large enough capacitor to charge the internal sampling capacitor with very little ripple. However, for AC use, AIN must be driven by a wideband buffer (at least 10MHz), which must be stable with the ADC's capacitive load (in parallel with any AIN bypass capacitor used) and also settle quickly. An example of this circuit using the MAX4434 is given in Figure 9.

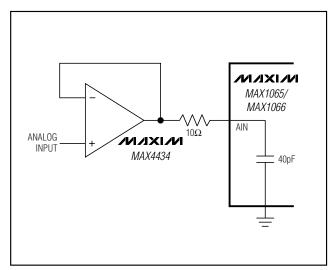


Figure 9. MAX1065/MAX1066 Fast Settling Input Buffer



### Layout, Grounding, and Bypassing

For best performance, use printed circuit boards. Do not run analog and digital lines parallel to each other, and do not lay out digital signal paths underneath the ADC package. Use separate analog and digital ground planes with only one point connecting the two ground systems (analog and digital) as close to the device as possible.

Route digital signals far away from sensitive analog and reference inputs. If digital lines must cross analog lines, do so at right angles to minimize coupling digital noise onto the analog lines. If the analog and digital sections share the same supply, then isolate the digital and analog supply by connecting them with a low-value ( $10\Omega$ ) resistor or ferrite bead.

The ADC is sensitive to high-frequency noise on the AV<sub>DD</sub> supply. Bypass AV<sub>DD</sub> to AGND with a 0.1µF capacitor in parallel with a 1µF to 10µF low-ESR capacitor and the smallest capacitor closest to the device. Keep capacitor leads short to minimize stray inductance.

### Definitions

### **Integral Nonlinearity**

Integral nonlinearity (INL) is the deviation of the values on an actual transfer function from a straight line. This straight line can be either a best-straight-line fit or a line drawn between the end points of the transfer function, once offset and gain errors have been nullified. The static linearity parameters for the MAX1065/MAX1066 are measured using the end-point method.

### **Differential Nonlinearity**

Differential nonlinearity (DNL) is the difference between an actual step width and the ideal value of 1LSB. A DNL error specification of 1LSB guarantees no missing codes and a monotonic transfer function.

### **Aperture Jitter and Delay**

Aperture jitter is the sample-to-sample variation in the time between samples. Aperture delay is the time between the rising edge of the sampling clock and the instant when the actual sample is taken.

### Signal-to-Noise Ratio

For a waveform perfectly reconstructed from digital samples, signal-to-noise ratio (SNR) is the ratio of the full-scale analog input (RMS value) to the RMS quantization error (residual error). The ideal, theoretical minimum analog-to-digital noise is caused by quantization noise error only and results directly from the ADC's resolution (N-bits):

 $SNR = (6.02 \times N + 1.76) dB$ 

where N = 14 bits.

In reality, there are other noise sources besides quantization noise: thermal noise, reference noise, clock jitter, etc. SNR is computed by taking the ratio of the RMS signal to the RMS noise, which includes all spectral components minus the fundamental, the first five harmonics, and the DC offset.

### Signal-to-Noise Plus Distortion

Signal-to-noise plus distortion (SINAD) is the ratio of the fundamental input frequency's RMS amplitude to the RMS equivalent of all the other ADC output signals.

$$SINAD(dB) = 20 \times log \left[ \frac{Signal_{RMS}}{(Noise + Distortion)_{RMS}} \right]$$

### **Effective Number of Bits**

Effective number of bits (ENOB) indicates the global accuracy of an ADC at a specific input frequency and sampling rate. An ideal ADC's error consists of quantization noise only. With an input range equal to the full-scale range of the ADC, calculate the effective number of bits as follows:

$$ENOB = \frac{SINAD - 1.76}{6.02}$$

### **Total Harmonic Distortion**

Total harmonic distortion (THD) is the ratio of the RMS sum of the first five harmonics of the input signal to the fundamental itself. This is expressed as:

THD = 20 × log 
$$\frac{\left(\sqrt{V_2^2 + V_3^2 + V_4^2 + V_5^2}\right)}{V_1}$$

where  $V_1$  is the fundamental amplitude and  $V_2$  through  $V_5$  are the 2nd- through 5th-order harmonics.

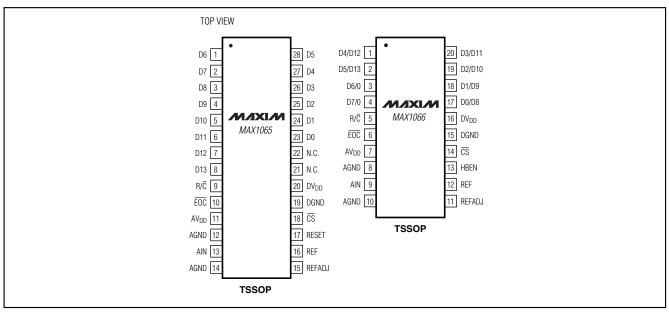
### **Spurious-Free Dynamic Range**

Spurious-free dynamic range (SFDR) is the ratio of the RMS amplitude of the fundamental (maximum signal component) to the RMS value of the next largest frequency component.

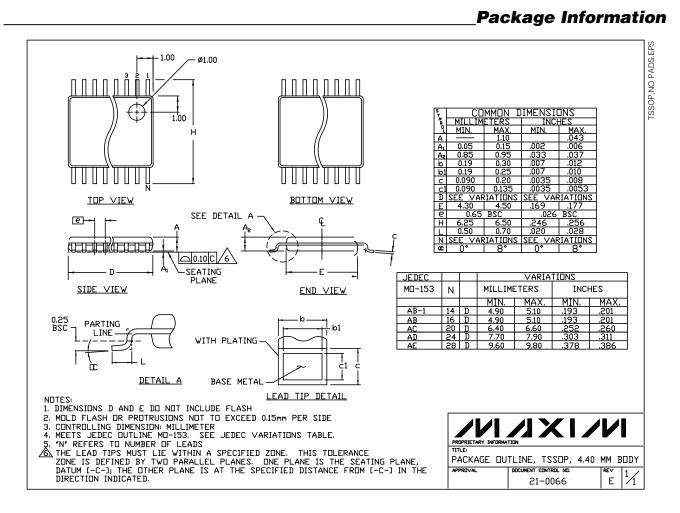
### Chip Information

TRANSISTOR COUNT: 15,140 PROCESS: BICMOS





MAX1065/MAX1066



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14

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